



QUICKSWITCH® PRODUCTS
HIGH-SPEED CMOS DUAL
BUS SWITCH WITH INDIVIDUAL
ACTIVE LOW ENABLES

IDTQS3306A

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- Very low ON resistance (5Ω typical)
- Zero propagation delay, zero added ground bounce
- Fast turn-on/turn-off time
- Undershoot clamp diodes on all switch and control inputs
- Available in SOIC package

APPLICATIONS:

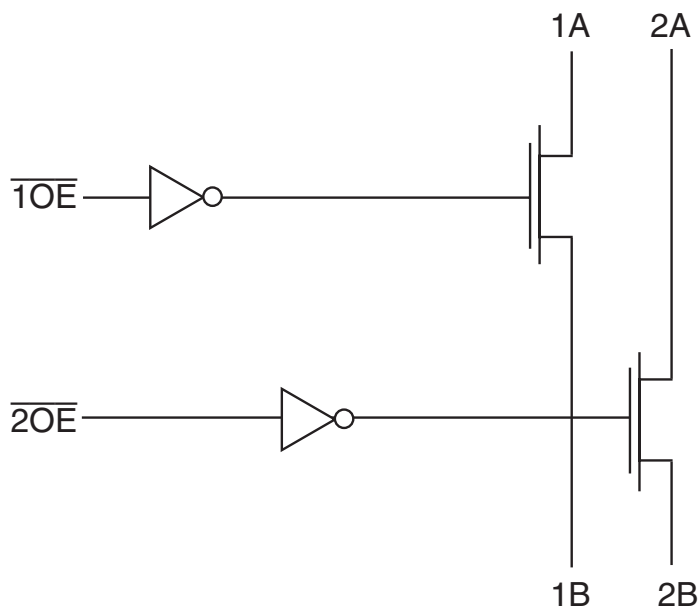
- Line control
- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Power conservation
- Capacitance reduction and isolation
- Clock gating
- Bus isolation
- Signal suppression/blinking

DESCRIPTION:

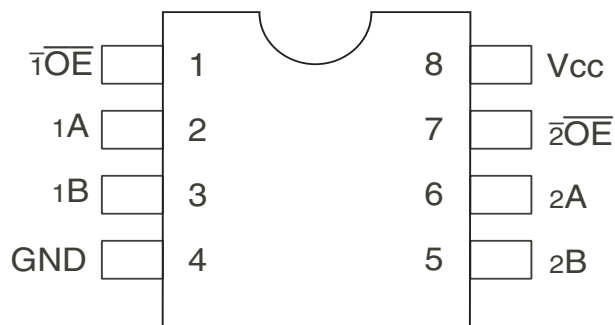
The QS3306A provides a set of two high-speed low resistance (3Ω typical) CMOS switches connecting inputs to outputs without propagation delay and without generating additional ground bounce noise. Individual enables ($\overline{OE}$) are used to turn on the switches. The QS3306A is ideal for signal and control switching since the device adds no noise, ground bounce, propagation delay, or significant power consumption to the system. The QS3306A can also be used for analog switching applications such as video.

The QS3306A is characterized for operation at -40°C to $+85^{\circ}\text{C}$.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



SOIC (S1)
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	-0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage Vs	-0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage VIN	-0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
IOUT	DC Output Current	120	mA
PMAX	Maximum Power Dissipation	0.5	W
TSTG	Storage Temperature	-65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- Vcc terminals.
- All terminals except Vcc .

CAPACITANCE (TA = +25°C, f = 1MHz, VIN = 0V, VOUT = 0V)

Pins	Typ.	Max. ⁽¹⁾	Unit
OE (Inputs)	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

- This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	I/O	Description
1A - 2A	I/O	Bus A
1B - 2B	I/O	Bus B
1OE - 2OE	I	Switch Enable

FUNCTION TABLE⁽¹⁾

xOE	xA	xB	Function
L	H	H	Connect
L	L	L	Connect
H	X	X	Disconnect

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

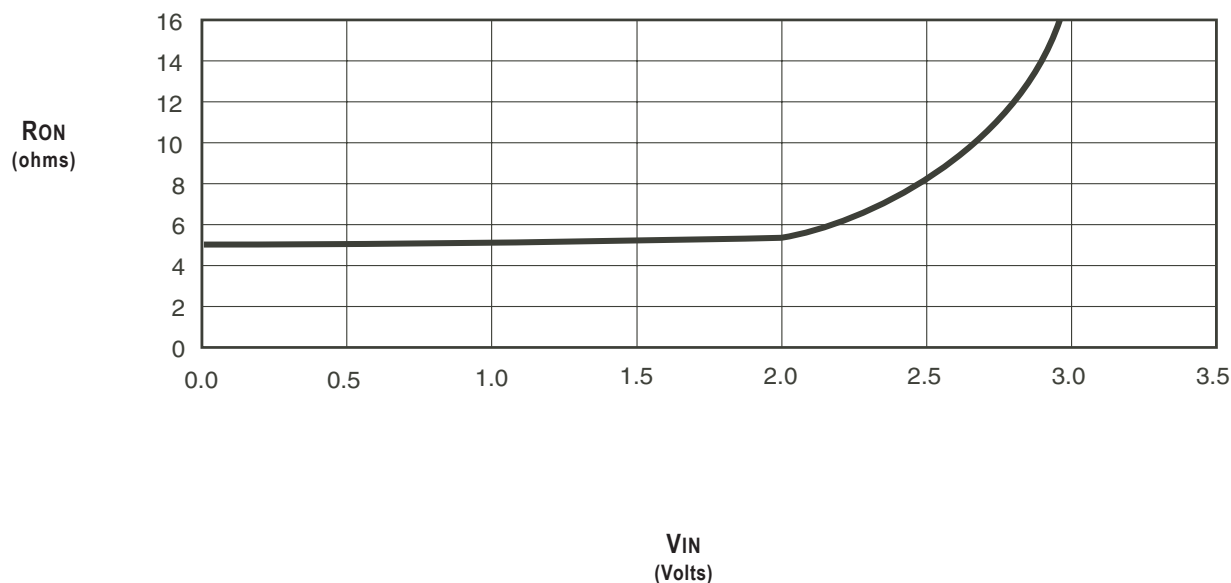
Industrial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 5\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	—	—	V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
I_{IN}	Input Leakage Current (Control Inputs)	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	—	± 1	μA
I_{OZ}	Off-State Current (Hi-Z)	$0\text{V} \leq V_{OUT} \leq V_{CC}$, Switches OFF	—	—	± 1	μA
R_{ON}	Switch ON Resistance ⁽²⁾	$V_{CC} = \text{Min.}$, $V_{IN} = 0\text{V}$, $I_{ON} = 30\text{mA}$	—	5	7	Ω
		$V_{CC} = \text{Min.}$, $V_{IN} = 2.4\text{V}$, $I_{ON} = 15\text{mA}$	—	10	15	
V_P	Pass Voltage ⁽³⁾	$V_{IN} = V_{CC} = 5\text{V}$, $I_{OUT} = -5\mu\text{A}$	3.7	4	4.2	V

NOTES:

1. Typical values are at $V_{CC} = 5\text{V}$ and $T_A = 25^{\circ}\text{C}$.
2. R_{ON} is guaranteed but not production tested.
3. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs V_{IN} AT $V_{CC} = 5\text{V}$



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
I _{CCQ}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC} , f = 0	3	μA
ΔI _{CC}	Power Supply Current per Input HIGH ⁽²⁾	V _{CC} = Max., V _{IN} = 3.4V, f = 0	1	mA
I _{CCD}	Dynamic Power Supply Current per MHz ⁽³⁾	V _{CC} = Max., A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	0.25	mA/MHz

NOTES:

- For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- Per TTL-driven input (V_{IN} = 3.4V, control inputs only). A and B pins do not contribute to ΔI_{CC}.
- This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C, V_{CC} = 5V ± 5%

C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Typ.	Max.	Unit
t _{PLH} t _{PHL}	Data Propagation Delay ⁽²⁾ xA to xB	—	—	0.25 ⁽³⁾	ns
t _{PZL} t _{PZH}	Switch Turn-On Delay OE to xA/xB	1.5	—	6.5	ns
t _{PLZ} t _{PHZ}	Switch Turn-Off Delay ⁽²⁾ OE to xA/xB	1.5	—	5.5	ns

NOTES:

- Minimums are guaranteed but not production tested.
- This parameter is guaranteed but not production tested.
- The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns at C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION

QS	XXXXX Device Type	XX Package	X Process	X	
				Blank	Tube or Tray
				8	Tape and Reel
				Blank	Industrial (-40°C to +85°C)
				S1G	8 pin Small Outline IC - Green
				3306A	High Speed CMOS Dual Bus Switch with Individual Active Low Enables



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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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